

CMH52N50/CMA52N50

500V, 100mΩ typ., 52A N-Channel MOSFET

General Description

The 52N50 uses advanced planar stripe DMOS technology and design to provide excellent RDS(ON). These devices are well suited for high-efficiency switched mode power supplies and active power factor correction.

Features

- Improved dv/dt capability
- 100% avalanche tested
- RoHS Compliant

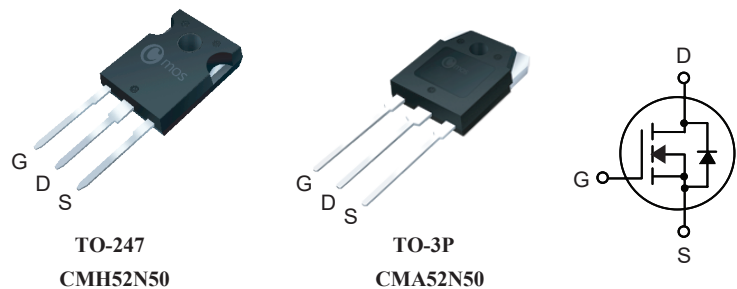
Product Summary

BVDSS	R _{DS(on)} max.	ID
500V	110mΩ	52A

Applications

- Switch Mode Power Supply
- PFC

TO-247/TO-3P Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	500	V
V _{GS}	Gate-Source Voltage	±30	V
I _D @T _C =25°C	Continuous Drain Current	52	A
I _D @T _C =100°C	Continuous Drain Current	40	A
I _{DM}	Pulsed Drain Current	208	A
EAS	Single Pulse Avalanche Energy <small>(Note 1)</small>	4205	mJ
P _D @T _C =25°C	Total Power Dissipation	625	W
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _J	Operating Junction Temperature Range	-55 to 150	°C

Thermal Data

Symbol	Parameter	Typ.	Max.	Unit
R _{θJA}	Thermal Resistance Junction-ambient	---	40	°C/W
R _{θJC}	Thermal Resistance Junction-case	---	0.2	°C/W

Electrical Characteristics ($T_J=25^{\circ}\text{C}$, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	500	---	---	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance	$V_{GS}=10V, I_D=25A$	---	100	110	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}, I_D=250\mu A$	2.0	---	4.0	V
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=500V, V_{GS}=0V$	---	---	10	uA
I_{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm 30V, V_{DS}=0V$	---	---	±100	nA
g_{fs}	Forward Transconductance	$V_{DS}=25V, I_D=25A$	---	44	---	S
R_g	Gate Resistance	$V_{DS}=0V, V_{GS}=0V, f=1\text{MHz}$	---	0.8	---	Ω
Q_g	Total Gate Charge	$V_{DS}=400V, I_D=23A$ $V_{GS}=10V$ (note 2,3)	---	180	---	nC
Q_{gs}	Gate-Source Charge		---	39	---	
Q_{gd}	Gate-Drain Charge		---	57	---	
$T_{d(on)}$	Turn-On Delay Time	$V_{DD}=250V, I_D=23A$ $R_G=25\Omega$ (note 2,3)	---	62	---	ns
T_r	Rise Time		---	24	---	
$T_{d(off)}$	Turn-Off Delay Time		---	188	---	
T_f	Fall Time		---	23	---	
C_{iss}	Input Capacitance	$V_{DS}=25V, V_{GS}=0V, f=1\text{MHz}$	---	10400	---	pF
C_{oss}	Output Capacitance		---	700	---	
C_{rss}	Reverse Transfer Capacitance		---	65	---	

Diode Characteristics

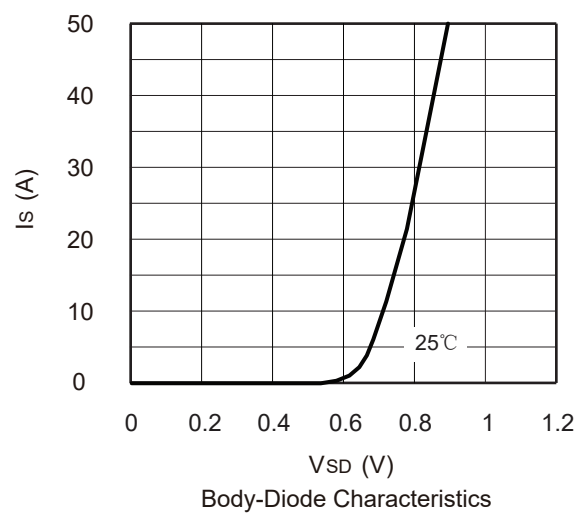
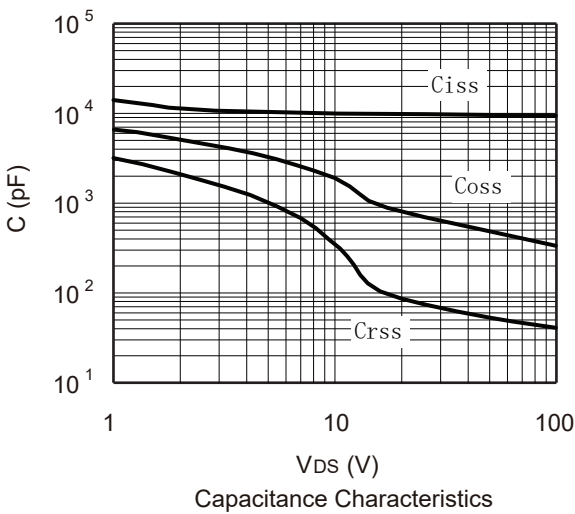
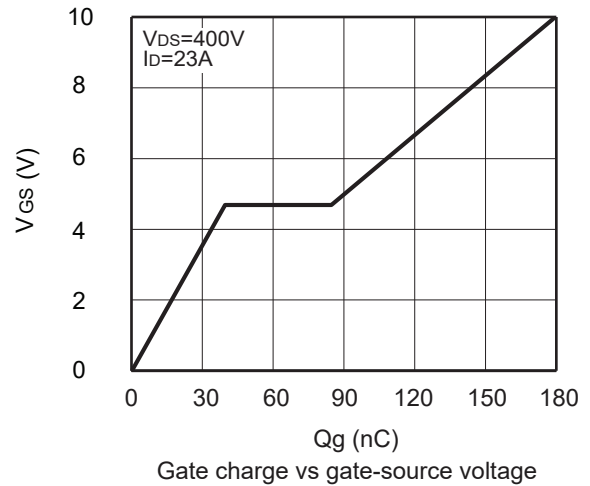
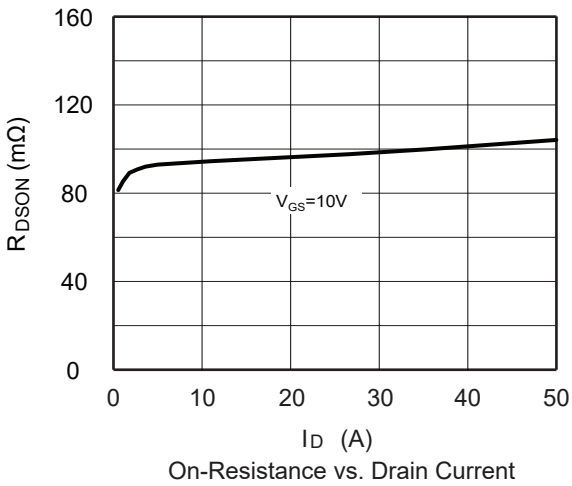
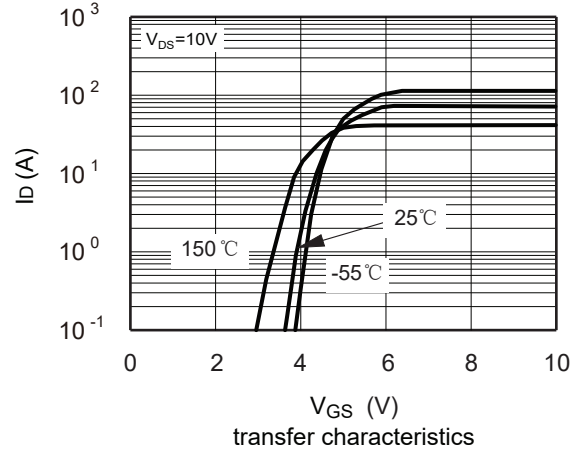
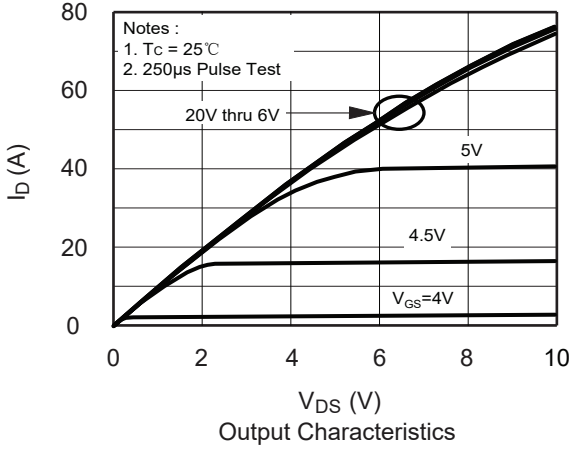
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_S	Continuous Source Current	$V_G=V_D=0V$, Force Current	---	---	52	A
I_{SM}	Pulsed Source Current		---	---	208	A
V_{SD}	Diode Forward Voltage	$V_{GS}=0V, I_S=52A$	---	0.88	1.5	V
t_{rr}	Reverse Recovery Time	$I_S=50A, V_{GS}=0V$	---	487	---	ns
Q_{rr}	Reverse Recovery Charge	$di/dt=100A/\mu s$ (note 2,3)	---	6.9	---	μC

Note :

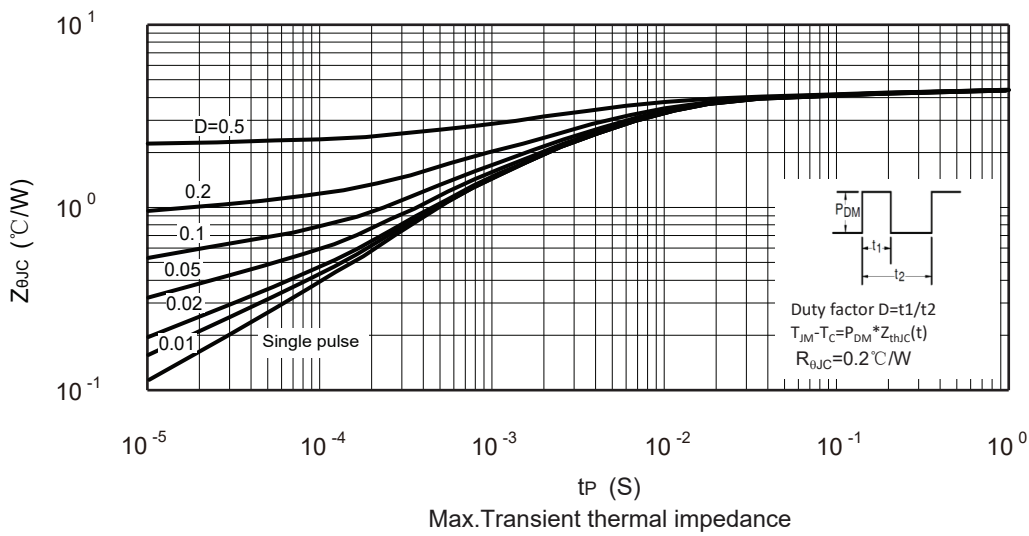
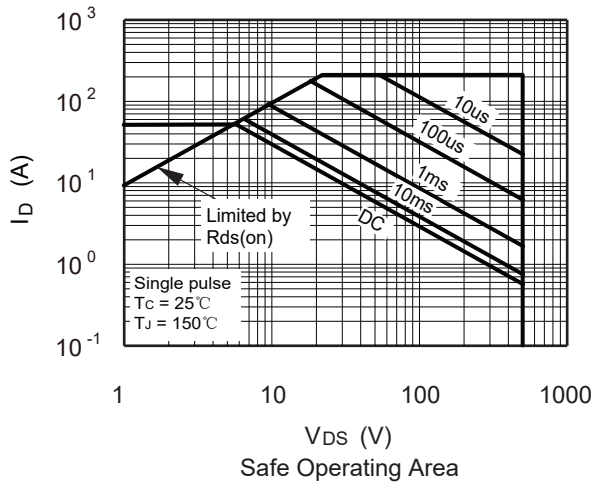
- 1.The EAS data shows Max. rating .The test condition is $V_{DS}=100V, V_{GS}=10V, L=10\text{mH}, I_{AS}=29A$.
2. Pulse test: Pulse width≤300us, Duty cycles≤2%.
3. Essentially independent of operating temperature typical characteristics.

This product has been designed and qualified for the consumer market.
Cmos assumes no liability for customers' product design or applications.
Cmos reserves the right to improve product design, functions and reliability without notice. Please refer to the latest version of specification.

Typical Characteristics



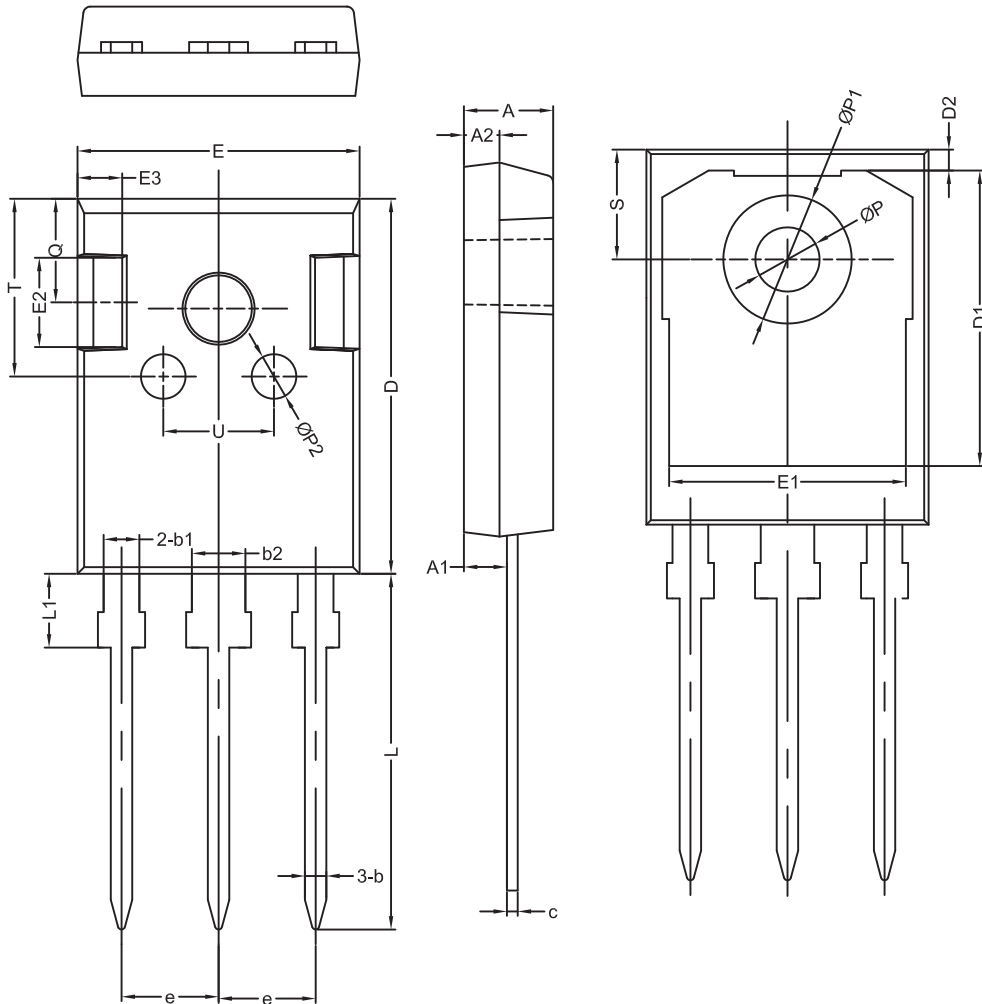
Typical Characteristics



Package Dimension

TO-247

Unit :mm

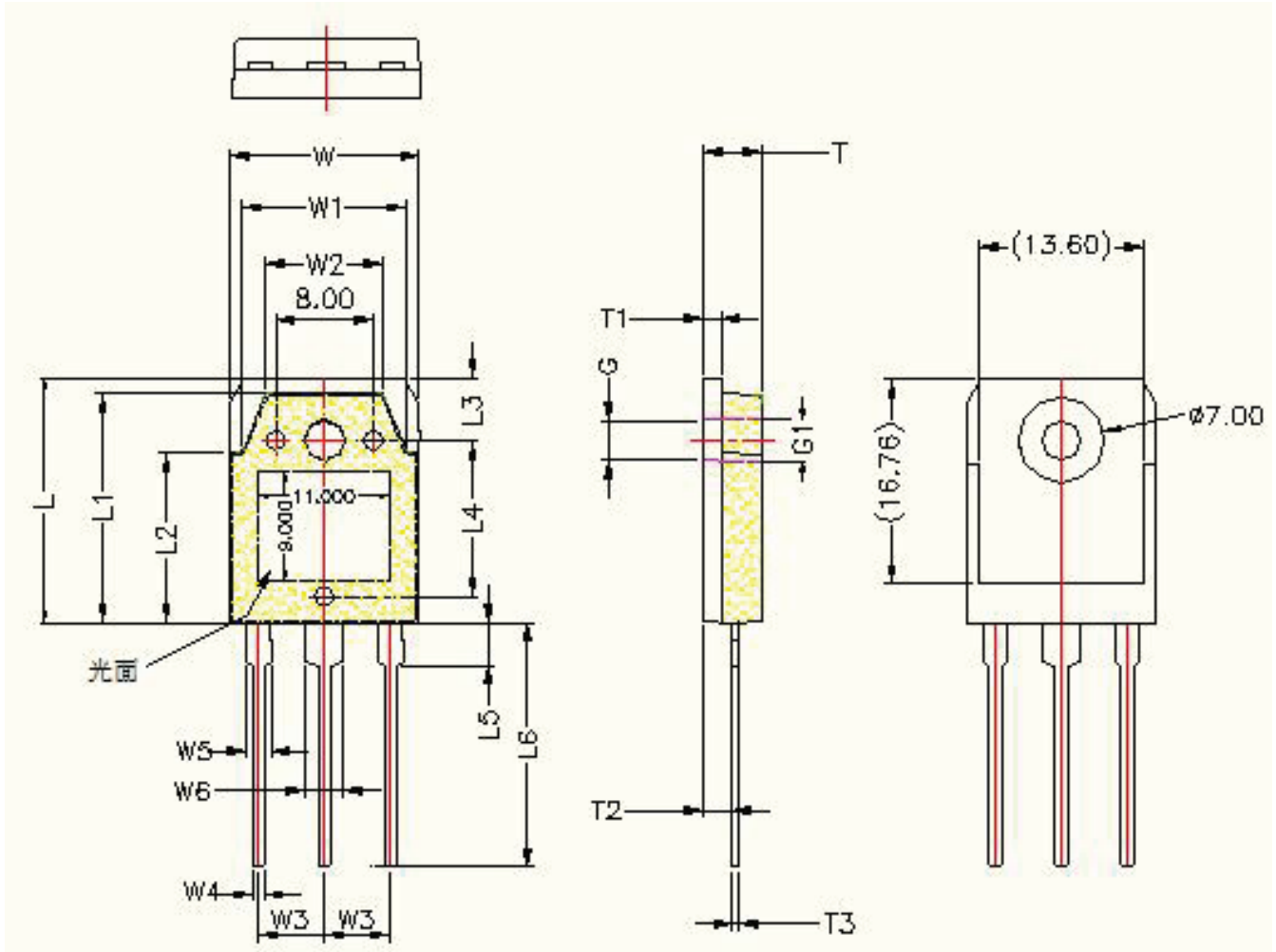


符号	机械尺寸/mm			符号	机械尺寸/mm		
	最小值	典型值	最大值		最小值	典型值	最大值
A	4.80	5.00	5.20	E2		5.00	
A1	2.21	2.41	2.61	E3		2.50	
A2	1.90	2.00	2.10	e		5.44	
b	1.10	1.20	1.35	L	19.42	19.92	20.42
b1		2.00		L1		4.13	
b2		3.00		P	3.50	3.60	3.70
c	0.55	0.60	0.75	P1		7.19	
D	20.80	21.00	21.20	P2		2.50	
D1		16.55		Q		5.80	
D2		1.20		S	6.05	6.15	6.25
E	15.60	15.80	16.0	T		10.00	
E1		13.30		U		6.20	

Package Dimension

TO-3P

Unit :mm



Symbol	Dimensions	Symbol	Dimensions	Symbol	Dimensions
W	15.60±0.3	L	19.90±0.3	T	4.80±0.3
W1	13.60±0.3	L1	18.70±0.3	T1	1.50±0.3
W2	9.60±0.3	L2	13.90±0.3	T2	2.40±0.3
W3	5.45(TYP)	L3	5.00±0.3	T3	0.60±0.3
W4	1.00±0.3	L4	12.76±0.3	G	Ø3.25±0.3
W5	2.10±0.2	L5	3.50±0.3	G1	Ø3.58±0.3
W6	3.10±0.2	L6	20.00±0.3		